Features

- Low R_{DS(on)}
- Ultra-low Q_G For High Efficiency
- Logic Level
- Light Weight 0.113 grams
- New Compact Hermetic Package
- Source Sense Pin
- Total Dose
 - Rated to 300 krad
- Single Event
 - SEE immunity for LET of 83.7 MeV/mg/cm² with V_{DS} up to 100% of rated Breakdown
- Low Dose Rate at 100 mRad/sec
 - Maintains Pre-Rad specification
- Neutron
 - Maintains Pre-Rad specification for up to 1 x 10¹³ Neutrons/cm²

Application

- Commercial Satellite EPS & Avionics
- Deep Space Probes
- High Speed Rad Hard DC-DC Conversion
- Rad Hard Motor Controllers

Thermal Characteristics

Symbol	Parameter-Conditions	Value	Units
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (Note 3)	64	°C/W
$R_{\theta JC}$	Thermal Resistance Junction to Case	16.35	C/VV





FBG30N04C

Rad Hard eGaN[®] HEMT 300 V, 4 A, 400 mΩ Surface Mount (FSMD-C)

Description

EPC Space FSMD-C series of eGaN® power switching HEMTs have been specifically designed for critical applications in the high reliability or commercial satellite space environments. These devices have exceptionally high electron mobility and a low temperature coefficient resulting in very low $R_{\text{DS(on)}}$ values. The lateral structure of the die provides for very low gate charge (Q_{G}) and extremely fast switching times. These features enable faster power supply switching frequencies resulting in higher power densities, higher efficiencies and more compact packaging.

I/O Pin Assignment (Bottom View)

Pin	Symbol	Description
1	G	Gate
2	D	Drain
3	SS	Source Sense
4	S	Source



Absolute Maximum Rating ($T_C = 25^{\circ}$ C unless otherwise noted)

Symbol	Parameter-Conditions	Value	Units
V _{DS}	Drain to Source Voltage (Note 1)	300	V
I _D	Continuous Drain Current ID @ $V_{GS} = 5 \text{ V}$, $T_C = 25^{\circ}\text{C}$, $R_{\theta JA} < 62 ^{\circ}\text{C/W}$	4	۸
I _{DM}	Single-Pulse Drain Current t _{pulse} ≤ 80 µs	12	Α
V _{GS}	Gate to Source Voltage (Note 2)	+6 / -4	V
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C
T _{sol}	Package Mounting Surface Temperature	260	°C
ESD	ESD Class	ΔΑ	



Electrical Characteristics ($T_C = 25$ °C unless otherwise noted. Typical (TYP) values are for reference only.)

Parameter	Symbol	Test Con	ditions	MIN	TYP	MAX	Units
Minimum Drain to Source Voltage	V _{DSMIN}	$V_G = 0 V$		300			V
Drain to Source Leakage	1	V _{DS} = 300 V	$T_C = 25^{\circ}C$	_	10	100	
Drain to Source Leakage	DSS	$V_{GS} = 0 V$	T _C = 125°C	-	240	500	
Gate to Source Forward Leakage	I _{GSSF}	V _{GS} = 5 V	T _C = 25°C	-	250	500	μΑ
Gate to Source Reverse Leakage	I _{GSSR}	V _{GS} = -4 V	T _C = 25°C	-60	-20		
Gate to Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 0.6 \text{ mA}$	T _C = 25°C	0.8	1.2	2.8	V
Gate to Source Threshold Voltage Temperature Coefficient	$\Delta V_{GS(th)}/\Delta T$	$V_{DS} = V_{GS}, I_{D} = 0.6 \text{ mA}$	-55°C < T _A < 25°C	_	0.5	_	mV/°C
Drain to Source Resistance (Note 4)	R _{DS(on)}	$I_D = 4 A, V_{GS} = 5 V$	T _C = 25°C	-	210	400	mΩ
Source to Drain Forward Voltage (Note 5)	V _{SD}	$I_S = 0.5 \text{ A}, V_G = 0 \text{ V}$	T _C = 25°C		1.75		V

Dynamic Characteristics ($T_C = 25^{\circ}C$ unless otherwise noted. Typical (TYP) values are for reference only.)

Parameter	Symbol	Test Conditions	MIN	TYP	MAX	Units
Input Capacitance	C _{ISS}			380	450	
Output Capacitance	C _{OSS}	f = 1 MHz, V _{DS} = 150 V, V _{GS} =0 V (Note 6)		48	60	pF
Reverse transfer Capacitance	C _{RSS}			2	4	
Gate Resistance	R _G	$f = 1 \text{ MHz}, V_{DS} = V_{GS} = 0 \text{ V}$		0.4		Ω
Total Gate Charge (Note 7)	Q_{G}	$I_D = 4 \text{ A}, V_{GS} = 5 \text{ V}, V_{DS} = 150 \text{ V}$		1.6	2.6	
Gate to Drain Charge (Note 7)	Q_{GD}	$I_D = 4 \text{ A}, V_{GS} = 5 \text{ V}, V_{DS} = 150 \text{ V}$		1.1	1.3	
Gate to Source Charge (Note 7)	Q_{GS}	$I_D = 4 \text{ A}, V_{GS} = 5 \text{ V}, V_{DS} = 150 \text{ V}$		0.9	1.7	nC
Output Charge (Note 8)	Q _{OSS}	$V_{GS} = 0 \text{ V}, V_{DS} = 150 \text{ V}$		40		
Source to Drain Recovery Charge	Q _{RR}	I _D = 4 A, V _{DS} = 150 V		<1		



Radiation Characteristics

EPC Space eGaN® HEMTs are tested according to MIL-STD-750 Method 1019 for total ionizing dose validation. Every manufacturing lot is tested for total ionizing dose of Gamma radiation with an in-situ bias for (i) $V_{GS} = 5 \text{ V}$, (ii) $V_{DS} = V_{GS} = 0 \text{ V}$ and (iii) $V_{DS} = 80\% \text{ B}_{VDSS}$.

Electrical Characteristics up to 300 krads ($T_C = 25^{\circ}$ C unless otherwise noted. Typical (TYP) values are for reference only.)

Parameter	Symbol	Test Conditions	MIN	TYP	MAX	Units
Maximum Drain to Source Voltage	V _{DSMAX}	$V_{GS} = 0 V$	_	_	300	V
Gate to Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 0.6$ mA	0.8	1.2	2.8	V
Drain to Source Leakage	I _{DSS}	$V_{DS} = 300 \text{ V}, V_{GS} = 0 \text{ V}$	_	10	290	
Gate to Source Forward Leakage	I _{GSS}	V _{GS} = 5 V	_	250	500	μA
Gate to Source Reverse Leakage	I _{GSS}	$V_{GS} = -4 \text{ V}$	_	-20	-100	
Drain to Source Resistance (Note 4)	R _{DS(on)}	$I_D = 4 A, V_{GS} = 5 V$	_	_	400	mΩ

Typical Single Event Effect Safe Operating Area

Note: All Single Event Effect testing is performed on the K-500 Cyclotron at Texas A&M University

Test	Environment				V _{DS} Vol	tage (V)
	lon	LET MeV/mg/cm ²	Range µm	Energy MeV	V _{GS} = 0 V	$V_{GS} = -4V$
See SOA	Xe	50	131	1653	300	300
-	Au	83.7	130	2482	300	300

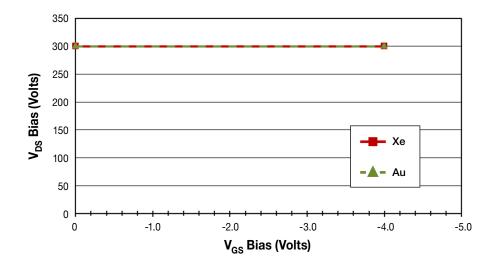


Figure 1. Typical Single Event Effect Safe Operating Area

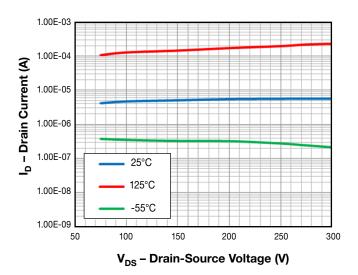


Figure 2. Typical Gate-Source Leakage Current vs. Ambient Temperature

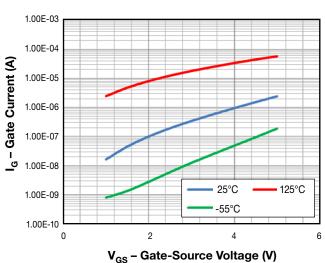


Figure 3. Typical Drain-Source Leakage Current vs. Ambient Temperature

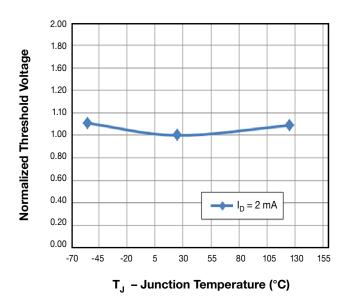


Figure 4. Normalized Threshold Voltage

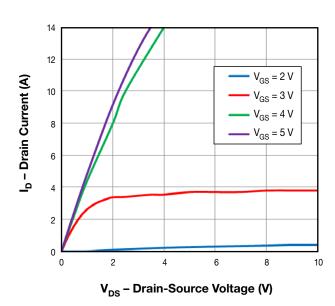
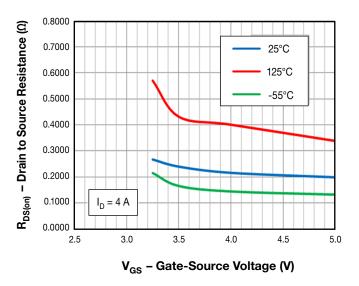


Figure 5. Typical Output Characteristics



1.0000 $R_{DS(on)}$ – Drain to Source Resistance (Ω) $I_{D} = 1.0 A$ 0.8000 $I_{D} = 2.5 A$ $I_{D} = 4.0 \text{ A}$ 0.6000 0.4000 0.2000 0.0000 2.0 2.5 3.0 3.5 4.0 4.5 5.0 V_{GS} - Gate-Source Voltage (V)

Figure 6. Typical Drain-Source ON Resistance vs. Gate-Source Voltage vs. Ambient Temperature

Figure 7. Typical Drain-Source ON Resistance vs. Gate-Source Voltage vs. Drain Current

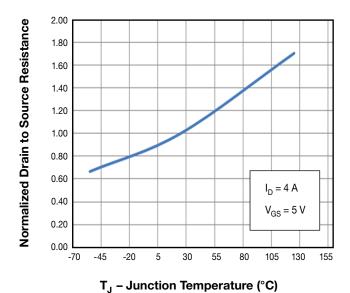
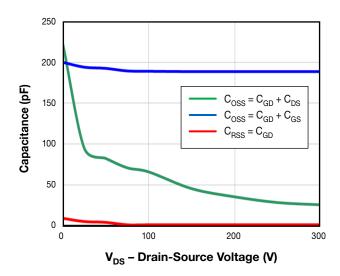


Figure 8. Typical Normalized Drain-Source ON Resistance vs. Ambient Temperature



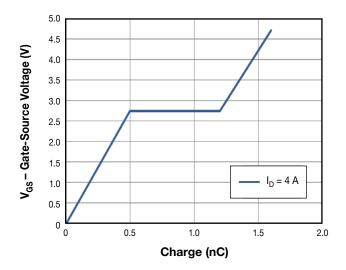


Figure 9. Typical Inter-Electrode Capacitance vs. Drain-Source Voltage

Figure 10. Typical Gate Charge vs. Drain Current

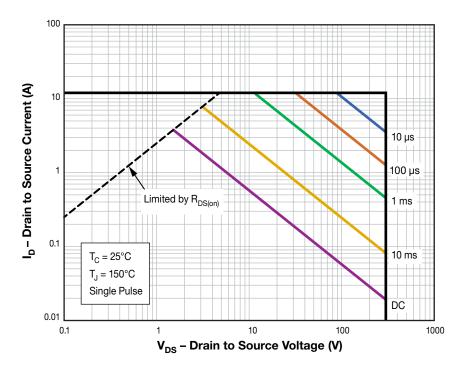


Figure 11. Safe Operating Area

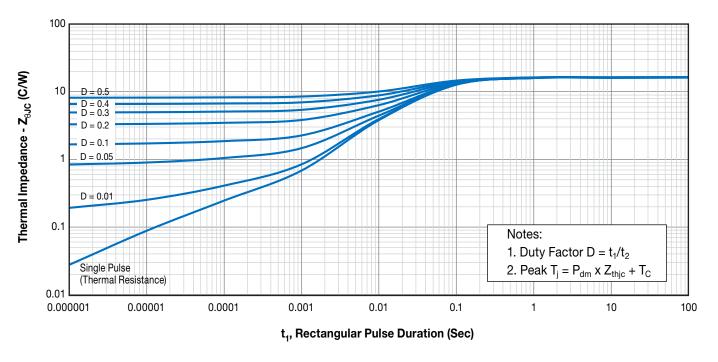


Figure 12. Transient Thermal Impedance, Junction to Case

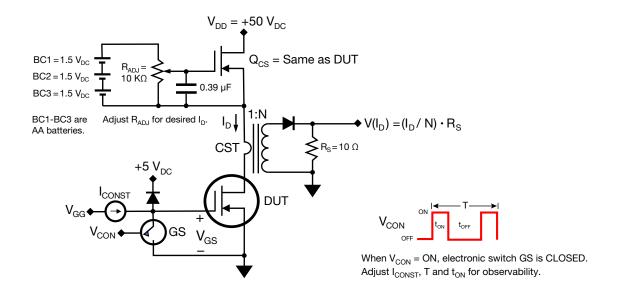


Figure 13. Charge Test Circuit

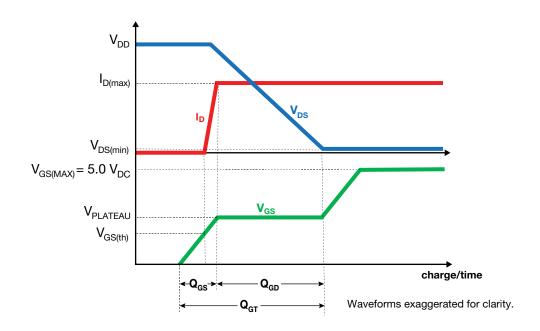
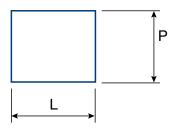
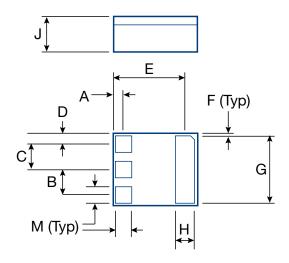


Figure 14. Typical Gate Charge Test Waveform



Package Outline and Dimensions

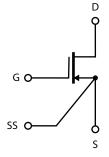




Symbol	Inch	nes	Millim	eters	Note
Oyboi	MIN	MAX	MIN	MAX	11010
Α	0.020	0.030	0.508	0.762	
В	0.055	0.065	1.473	1.727	
С	0.055	0.065	1.321	1.574	
D	0.020	0.030	0.508	0.762	
E	0.140	0.150	3.556	3.810	
F	0.005		0.127		Ref. only
G	0.155	0.165	3.937	4.191	
Н	0.035	0.045	0.889	1.143	
J	0.080	0.090	2.032	2.286	Ref. only
L	0.165	0.175	4.191	4.445	
М	0.035	0.045	0.889	1.143	
Р	0.165	0.175	4.191	4.445	

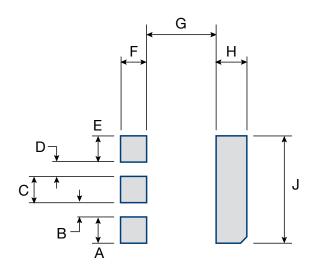
Standard Terminal Pad finish is a solder alloy of 63%Pb 37%Sn

Package Connections



NOTE: SS pin is connected directly to source of internal die.

FSMD-C Footprint for Printed Circuit Board Design



Symbol	Inch	nes	Millim	Note	
Oymbo.	MIN	MAX	MIN	MAX	11010
Α	0.038	0.048	0.965	1.219	
В	0.012	0.022	0.304	0.558	
С	0.041	0.051	1.041	1.295	
D	0.012	0.022	0.304	0.558	
E	0.038	0.048	0.965	1.219	
F	0.041	0.051	1.041	1.295	
G	0.069	0.079	1.752	2.006	
Н	0.041	0.051	1.041	1.295	
J	0.161	0.171	4.089	4.343	

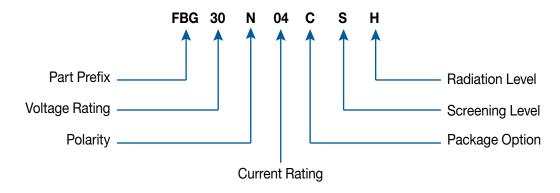


Notes

- Note 1. NEVER exceed the absolute maximum V_{DS} of the device otherwise permanent damage/destruction may result.
- Note 2. NEVER exceed the absolute maximum V_{GS} of the device otherwise permanent damage/destruction may result. We recommend use at no greater than +5 V as the HEMT is fully conducting at this point.
- Note 3. R_{0JA} measured with FSMD-C package mounted to double-sided PCB, 0.063" thickness with 1.0 square inches of copper area on the top (mounting side) and a flood etch (3 square inches) on the bottom side.
- Note 4. Measured using four wire (Kelvin) sensing and pulse measurement techniques. Measurement pulse width is 80 μs and duty cycle is 1%, maximum.
- Note 5. With pulse measurement width 100–380 μs.
- Note 6. $C_{ISS} = C_{GS} + C_{GD}$ with C_{DS} shorted. $C_{OSS} = C_{DS} + C_{GD}$. $C_{RSS} = C_{GD}$.
- Note 7. The gate charge parameters are measured using the circuit shown in Figure 11. Qs and associated components BT1, P1 and C1 form a high speed current source that serves as the test load for the DUT. A constant gate current (I_{const}) of 1.5-3 mA is provided to the Gate of the DUT during the time that the ground switch (I_{const}) is OFF (I_{const}). The DUT is switched ON and OFF using ground-sensed switch GS. The gate current is adjusted to yield the desired charge per unit time (I_{const} · time per division) on the measuring oscilloscope. The GS pulse drive ON time (I_{const}) is adjusted for the desired observability of the gate-source voltage (I_{const}) waveform. The maximum duty cycle of the ground switch (I_{const}) should be set to 1% maximum. Please note that all gate-related signals are referenced to the "Source Sense" pin on the package. At all times during the measurement, the maximum gate-source voltage is clamped to 5 I_{const}).
- Note 8. Guaranteed by design/device construction. Not tested.



EPC Space Part Number Information



Ordering Information Availability

Screening Options	Rad Assurance Options
1 character	1 character
C = Developmental Unit S = Space Level ¹	H = 1000 krad, LET = 84

Part Number	Screening Level	Shipping
FBG30N04C*C	Developmental Units	Wofflo travo
FBG30N04C*S	Space Level	Waffle trays

¹ Screening and qualification consistent to an equivalent MIL-PRF-19500 specification.

FBG30N04CC devices are intended for engineering development purposes only and are NOT intended to be used as flight units.

EPC Space Rad Hard HEMT are not sensitive to Total Ionizing Dose as such the H level covers the R,F,G radiation levels.



Screening Flow Equivalent to a MIL-PRF-19500 General Specification

Operation Test Test Methods Per Mil STD 760 Sample Size Space Level COT Pre-Assembly Probe Testing EPC SPACE Internal 100% ✓ ✓ You said inspection EPC SPACE Internal 100% ✓ ✓ Post-Assembly Die Shear 2,017 5 ✓ ✓ X-Ray 2076 5 ✓ ✓ Electricals 3411,3413,3421,3404 100% ✓ ✓ Temp Cycling 1051 100% ✓ ✓ Temp Cycling 2052 100% ✓ ✓ PiND 2052 100% ✓ ✓ Initial Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ ✓ HTGB 1042 Condition B 100% ✓ ✓ Interim Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ ✓ Sereening Final Electricals (High and Low Temperatures) 3411,3413,3421,3404 100% ✓ ✓ Per Procur		EPC SPACE Qual Flow Equivalen	t to a MIL-PRF-19500 Spec	ification	EPC SPACE Qual Flow Equivalent to a MIL-PRF-19500 Specification									
Pre-Assembly Visual inspection EPC SPACE Internal 100% ✓ Post-Assembly Die Shear 2,017 5 ✓ X-Ray 2076 5 ✓ ✓ Electricals 3411,3413,3421,3404 100% ✓ ✓ Temp Cycling 1051 100% ✓ ✓ PIND 2052 100% ✓ ✓ Initial Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ HTGB 1042 Condition B 100% ✓ Interim Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ Final Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ Final Electricals (High and Low Temperatures) 3411,3413,3421,3404 100% ✓ Percent Defective Allowable Per Procurement Specification 100% ✓ Percent Defective Allowable Per Procurement Specification 100% ✓ QutLiers Removal EPC SPACE Internal 100% ✓ X-RAY 2076	Operation	Test	Test Methods Per Mil STD 750	Sample Size	Space Level	СОТ								
Visual inspection EPC SPACE Internal 100% V V	Due Assembly	Probe Testing	EPC SPACE Internal	100%	✓	✓								
Name	Pre-Assembly	Visual inspection	EPC SPACE Internal	100%		✓								
Serilalization	Doot Assembly	Die Shear	2,017	5	✓	✓								
Electricals 3411,3413,3421,3404 100%	Post-Assembly	X-Ray	2076	5	✓	✓								
Temp Cycling		Serilialization		100%	✓									
Constant Acceleration 2006 100% ✓		Electricals	3411,3413,3421,3404	100%	✓	✓								
PIND 2052 100% ✓ Initial Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ HTGB 1042 Condition B 100% ✓ Interim Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ HTRB 1042 Condition A 240 Hours 100% ✓ Final Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ Final Electricals (High and Low Temperatures) 3411,3413,3421,3404 100% ✓ Deltas Per Procurement Specification 100% ✓ Percent Defective Allowable Per Procurement Specification 100% ✓ Dynamic RDSON EPC SPACE Internal 100% ✓ OutLiers Removal EPC SPACE Internal 100% ✓ X-RAY 2076 100% ✓ Tinning 100% ✓ Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		Temp Cycling	1051	100%	✓									
Initial Electricals (Read and Record) 3411,3413,3421,3404 100%		Constant Acceleration	2006	100%	✓									
HTGB 1042 Condition B 100% ✓ Interim Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ HTRB 1042 Condition A 240 Hours 100% ✓ Final Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ Final Electricals (High and Low Temperatures) 3411,3413,3421,3404 100% ✓ Deltas Per Procurement Specification 100% ✓ Percent Defective Allowable Per Procurement Specification 100% ✓ OutLiers Removal EPC SPACE Internal 100% ✓ X-RAY 2076 100% ✓ Tinning 100% ✓ Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		PIND	2052	100%	✓									
Interim Electricals (Read and Record)		Initial Electricals (Read and Record)	3411,3413,3421,3404	100%	✓									
HTRB		HTGB	1042 Condition B	100%	✓									
Screening Final Electricals (Read and Record) 3411,3413,3421,3404 100% ✓ Final Electricals (High and Low Temperatures) 3411,3413,3421,3404 100% ✓ Deltas Per Procurement Specification 100% ✓ Percent Defective Allowable Per Procurement Specification 100% ✓ Dynamic RDSON EPC SPACE Internal 100% ✓ OutLiers Removal EPC SPACE Internal 100% ✓ X-RAY 2076 100% ✓ Tinning 100% ✓ Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		Interim Electricals (Read and Record)	3411,3413,3421,3404	100%	✓									
Final Electricals (High and Low Temperatures) 3411,3413,3421,3404 100% Per Procurement Specification Per Procurement Specification 100% Dynamic RDSON EPC SPACE Internal OutLiers Removal EPC SPACE Internal 100% X-RAY 2076 100% Tinning 100% Hermetic Seal, Fine & Gross Leak 1071 100% Final Electricals 3411,3413,3421,3404 100% Final Electricals		HTRB	1042 Condition A 240 Hours	100%	✓									
DeltasPer Procurement Specification100%✓Percent Defective AllowablePer Procurement Specification100%✓Dynamic RDSONEPC SPACE Internal100%✓OutLiers RemovalEPC SPACE Internal100%✓X-RAY2076100%✓Tinning100%✓Hermetic Seal, Fine & Gross Leak1071100%✓Final Electricals3411,3413,3421,3404100%✓	Screening	Final Electricals (Read and Record)	3411,3413,3421,3404	100%	✓									
Percent Defective Allowable Per Procurement Specification 100% ✓ Dynamic RDSON EPC SPACE Internal 100% ✓ OutLiers Removal EPC SPACE Internal 100% ✓ X-RAY 2076 100% ✓ Tinning 100% ✓ Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		Final Electricals (High and Low Temperatures)	3411,3413,3421,3404	100%	✓									
Dynamic RDSON EPC SPACE Internal 100% ✓ OutLiers Removal EPC SPACE Internal 100% ✓ X-RAY 2076 100% ✓ Tinning 100% ✓ Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		Deltas	Per Procurement Specification	100%	✓									
OutLiers Removal EPC SPACE Internal 100% ✓ X-RAY 2076 100% ✓ Tinning 100% ✓ Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		Percent Defective Allowable	Per Procurement Specification	100%	✓									
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Tinning 100% ✓ Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		OutLiers Removal	EPC SPACE Internal	100%	✓									
Hermetic Seal, Fine & Gross Leak 1071 100% ✓ Final Electricals 3411,3413,3421,3404 100% ✓		X-RAY	2076	100%	✓									
Final Electricals 3411,3413,3421,3404 100% ✓		Tinning		100%	✓									
		Hermetic Seal, Fine & Gross Leak	1071	100%	✓									
		Final Electricals	3411,3413,3421,3404	100%	✓									
A-2 DC Static Tests at 25°C 3411,3413,3421,3404 116 ✓		A-2 DC Static Tests at 25°C	3411,3413,3421,3404	116	✓									
		A-3 High & Low Temp DC Static Tests	3411,3413,3421,3404	116	✓									
A-7 Gate Charges 3471 Condition B 45	(Conformance)	A-7 Gate Charges	3471 Condition B	45	✓									
A-7 Capacitance 3473 45 ✓		A-7 Capacitance	3473	45	✓									
Group B Inspection (Conformance) B-1, B-2, B-3, B-4, B-5 Sample base equivalent to a MIL-PRF-19500 flow or as required by procurement specificcation	• •	B-1, B-2, B-3, B-4, B-5	Sample base equivalent to a MIL-PRF-19500 flow or as required by											
Group C Inspection (Conformance) C-1, C-2, C-3, C-4, C-6, C-7 Sample base performed yearly per package style equivalent to a MIL-PRF-19500 flow or as required by procurement specification		C-1, C-2, C-3, C-4, C-6, C-7												
Group D Inspection TID 1019 15 ✓	(Conformance) Group D Inspection	TID	1019	15	✓									
(0(SEE	1080	5	✓									
Group E Inspection (Qualification E-1, E-2, E-5, E-6 E-7 Performed during product introduction or a major process change equivalent to a MIL-PRF-19500 flow or as required by		E-1, E-2, E-5, E-6 E-7				nge								
Inspection) E8 Switching procurement specification		E8 Switching												



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Revisions

Datasheet Revision	Product Status
REV P#	Proposal/development
REV Q#	Characterization and Qualification
M-700-007-F	Production Released

Information subject to change without notice.

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